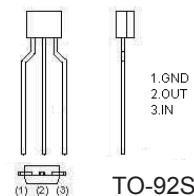


SOT-323 Digital transistors (built-in resistors)

Features

- DIGITAL TRANSISTOR (NPN)



MECHANICAL DATA

- Case: TO-92S Small Outline Plastic Package
- Polarity: Color band denotes cathode end
- Mounting Position: Any

ABSOLUTE MAXIMUM RATINGS

@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Limits (DTC143ESA)		Unit
Supply voltage	V _{CC}	50		V
Input voltage	V _{IN}	-10~+30		V
Output current	I _O	100		mA
	I _{C(MAX)}	100		
Power dissipation	P _d	300		mW
Junction temperature	T _j	150		°C
Storage temperature	T _{stg}	-55--150		°C

Electrical Specification (T_A=25°C unless otherwise specified)

Parameter	Symbol	Mi	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			0.5	V	V _{CC} =5V ,I _O =100μA
	V _{I(on)}	3				V _O =0.3V ,I _O =20 mA
Output voltage	V _{O(on)}			0.3	V	I _O /I _I =10mA/0.5mA
Input current	I _I			1.8	mA	V _I =5V
Output current	I _{O(off)}			0.5	μA	V _{CC} =50V ,V _I =0
DC current gain	G _I	20				V _O =5V ,I _O =10mA
Input resistance	R _I	3.29	4.7	6.11	KΩ	
Resistance ratio	R ₂ /R ₁	0.8	1	1.2		
Transition frequency	f _T		250		MHz	V _O =10V ,I _O =5mA,f=100MHz

RATINGS AND CHARACTERISTIC CURVES

■ Typical Characteristics

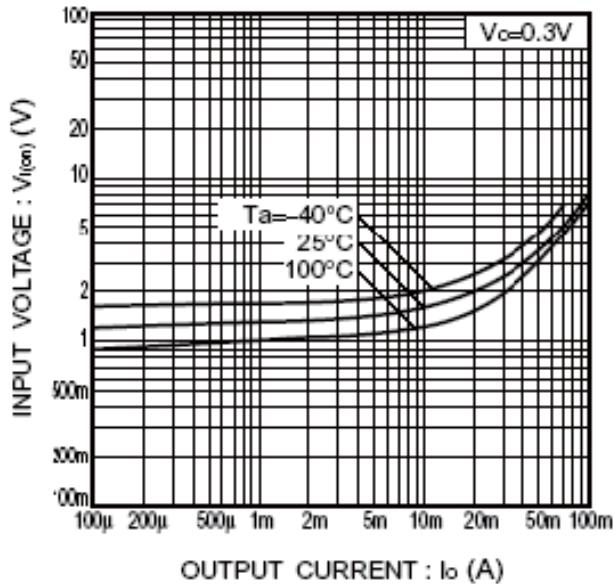


Fig.1 Input voltage vs. output current
(ON characteristics)

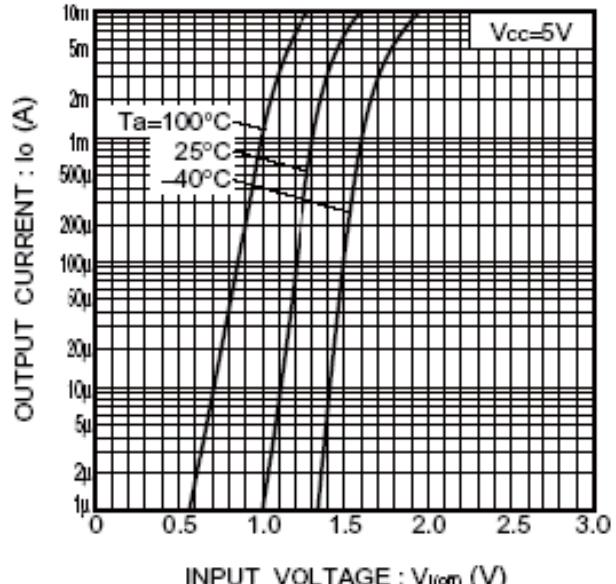


Fig.2 Output current vs. input voltage
(OFF characteristics)

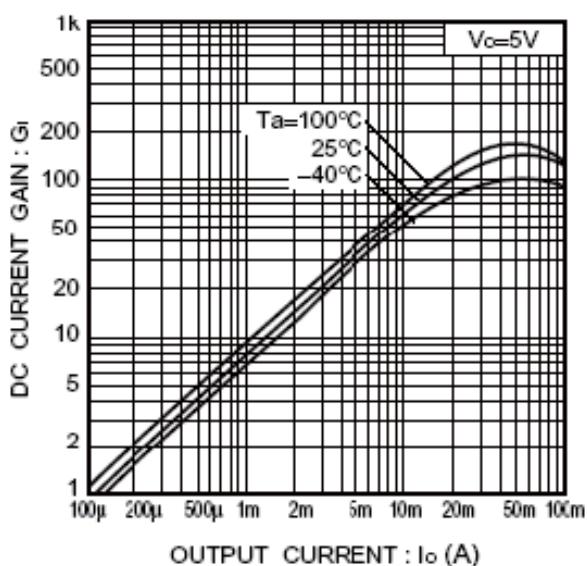


Fig.3 DC current gain vs. output current

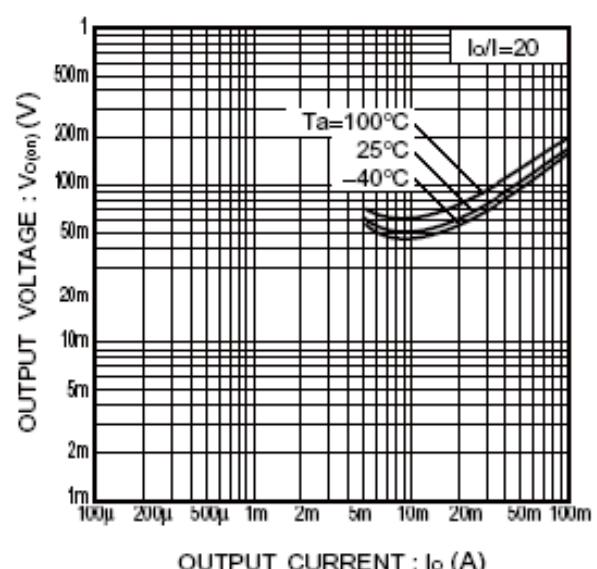


Fig.4 Output voltage vs. output current